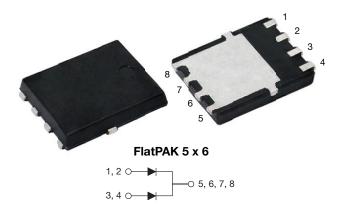
V15KL45C

Vishay General Semiconductor

High Current Density Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.32$ V at $I_F = 5$ A



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DESIGN SUPPORT TOOLS AVAILABLE

3D Models

| PRIMARY CHARACTERISTICS | | | | | |
|--|----------------|--|--|--|--|
| I _{F(AV)} | 2 x 7.5 A | | | | |
| V _{RRM} | 45 V | | | | |
| I _{FSM} | 140 A | | | | |
| V_F at I_F = 7.5 A (T_A = 125 °C) | 0.36 V | | | | |
| T _J max. | 150 °C | | | | |
| Package | FlatPAK 5 x 6 | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



Available

- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

MECHANICAL DATA

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

| MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|---|-----------------------------------|-------------|------|--|--|
| PARAMETER | SYMBOL | V15KL45C | UNIT | | |
| Device marking code | | 15L45C | | | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 45 | V | | |
| Maximum DC forward aureant par device | I _{F(AV)} ⁽¹⁾ | 15 A | А | | |
| Maximum DC forward current per device | I _{F(AV)} ⁽²⁾ | 5.6 | А | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 140 | А | | |
| Operating junction temperature range | T _J ⁽³⁾ | -40 to +150 | °C | | |
| Storage temperature range | T _{STG} | -55 to +150 | °C | | |

Notes

⁽¹⁾ With infinite heatsink

⁽²⁾ Free air, mounted on recommended pad area

 $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{0JA}

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V15KL45C



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| ELECTRICAL CHARACTERIST | ICS (T _A = 25 | °C unless oth | erwise notec | (k | | |
|---|---------------------------------|-------------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | I _F = 5 A | т ог «О | | 0.43 | - | |
| | $T_{A} = 25 \text{ °C}$ | V _F ⁽¹⁾ | 0.46 | 0.54 | V | |
| | I _F = 5 A | T _A = 125 °C | VE | 0.32 | - | V |
| | I _F = 7.5 A | | | 0.36 | 0.44 | |
| Deverse everent per diede | | T _A = 25 °C | I _R ⁽²⁾ | - | 2 | mA |
| Reverse current per diode | V _R = 45 V | T _A = 125 °C | | 16 | 40 | |
| Typical junction capacitance per diode | 4.0 V, 1 MHz | | CJ | 1700 | - | pF |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | |
|--|---------------------------------------|------|------|------|
| PARAMETER | SYMBOL | TYP. | MAX. | UNIT |
| Thermal resistance per device | R _{0JA} ⁽¹⁾⁽²⁾ 75 | - | °C/W | |
| | R _{0JM} ⁽³⁾ | 2.5 | 3.5 | 0/10 |

Notes

⁽¹⁾ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

 $^{(2)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ - junction-to-ambient

 $^{(3)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JM}$ - junction-to-mount

| ORDERING INF | DERING INFORMATION (Example) | | | | | |
|-------------------|------------------------------|------------------------|---------------|------------------------------------|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| V15KL45C-M3/H | 0.10 | Н | 1500 | 7" diameter plastic tape and reel | | |
| V15KL45C-M3/I | 0.10 | I | 6000 | 13" diameter plastic tape and reel | | |
| V15KL45CHM3/H (1) | 0.10 | Н | 1500 | 7" diameter plastic tape and reel | | |
| V15KL45CHM3/I (1) | 0.10 | I | 6000 | 13" diameter plastic tape and reel | | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

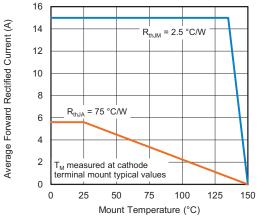


Fig. 1 - Maximum Forward Current Derating Curve

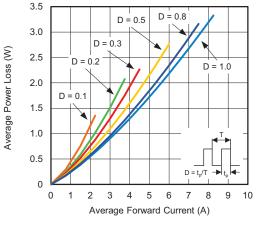


Fig. 2 - Forward Power Loss Characteristics

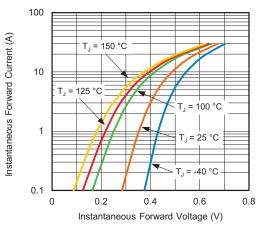


Fig. 3 - Typical Instantaneous Forward Characteristics

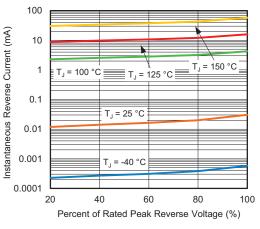


Fig. 4 - Typical Reverse Leakage Characteristics

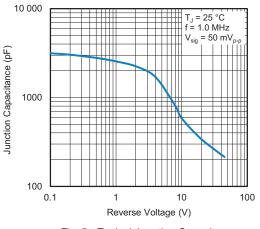


Fig. 5 - Typical Junction Capacitance

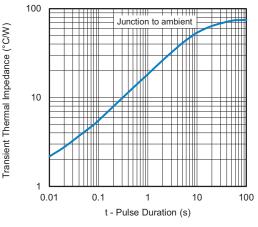


Fig. 6 - Typical Transient Thermal Impedance

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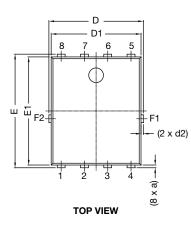
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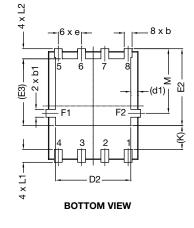


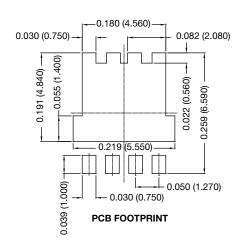
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

FlatPAK 5 x 6







| DIM | | INCHES | | | MILLIMETERS | | | |
|------|-------|-----------|-------|------|-------------|------|--|--|
| DIM. | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | | |
| А | 0.035 | 0.039 | 0.043 | 0.89 | 0.99 | 1.09 | | |
| (a) | - | 0.006 | - | - | 0.15 | - | | |
| b | 0.013 | 0.017 | 0.020 | 0.32 | 0.43 | 0.52 | | |
| b1 | 0.013 | 0.017 | 0.020 | 0.32 | 0.43 | 0.52 | | |
| С | 0.008 | - | 0.014 | 0.20 | - | 0.35 | | |
| D | 0.197 | 0.203 | 0.209 | 5.00 | 5.15 | 5.30 | | |
| D1 | 0.189 | 0.193 | 0.197 | 4.80 | 4.90 | 5.00 | | |
| D2 | 0.154 | 0.161 | 0.169 | 3.90 | 4.10 | 4.30 | | |
| (d1) | - | 0.016 | - | - | 0.40 | - | | |
| (d2) | - | 0.005 | - | - | 0.125 | - | | |
| E | 0.238 | 0.244 | 0.250 | 6.05 | 6.20 | 6.35 | | |
| E1 | 0.228 | 0.232 | 0.236 | 5.80 | 5.90 | 6.00 | | |
| E2 | 0.157 | 0.165 | 0.173 | 4.00 | 4.20 | 4.40 | | |
| (E3) | - | 0.144 | - | - | 3.65 | - | | |
| е | | 0.050 BSC | | | 1.27 BSC | | | |
| (K) | 0.039 | - | - | 1.00 | - | - | | |
| L1 | 0.019 | - | 0.043 | 0.48 | - | 1.10 | | |
| L2 | 0.012 | - | 0.031 | 0.30 | - | 0.80 | | |
| М | 0.128 | 0.138 | 0.148 | 3.25 | 3.50 | 3.75 | | |
| Θ | 0° | - | 10° | 0° | - | 10° | | |

Notes

• Dimensioning and tolerancing per ASME Y14.5-2009

• Dimensions D1 and E1 do not include mold flash or gate burrs

• Dimension (XX) means reference only

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